IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Leonard Forbes et al.

Title:

TECHNIQUE TO CONTROL TUNNELING CURRENTS IN DRAM CAPACITORS, CELLS,

AND DEVICES

Docket No.:

1303.017US2

Filed:

November 25, 2003

Examiner:

Unknown

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Serial No.: 10/721585 Due Date: N/A

Group Art Unit: 2825

We are transmitting herewith the following attached items (as indicated with an "X"):

A return postcard.

A Supplemental Information Disclosure Statement (2 pgs.), a Form 1449 (1 pg.), and a copy of one of 18 cited documents.

If not provided for in a separate paper filed herewith, Please consider this a PETITION FOR EXTENSION OF TIME for sufficient number of months to enter these papers and please charge any additional fees or credit overpayment to Deposit Account No. 19-0743.

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.

Customer Number 21186

Atty: David C. Peterson

Reg. No. 47,857

CERTIFICATE UNDER 37 CFR 1.8: The undersigned hereby certifies that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail, in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on this 121 day of May, 2004.

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.

(GENERAL)



S/N 10/721585 **PATENT**

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

applicant:

Leonard Forbes et al.

Examiner: Unknown

erial No.:

10/721585

Group Art Unit: 2825

November 25, 2003

Docket: 1303.017US2

TECHNIQUE TO CONTROL TUNNELING CURRENTS IN DRAM

CAPACITORS, CELLS, AND DEVICES

COMMUNICATION CONCERNING RELATED APPLICATION(S)

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Applicants would like to bring to the Examiner's attention the following related application(s) in the above-identified patent application:

Serial/Patent No.	Filing Date	Attorney Docket	<u>Title</u>
10/042924	January 9,	303.684US2	P-CHANNEL DYNAMIC FLASH
	2002		MEMORY CELLS WITH ULTRATHIN
		•	TUNNEL OXIDES
10/043065	January 9,	303.684US3	P-CHANNEL DYNAMIC FLASH
	2002	•	MEMORY CELLS WITH ULTRATHIN
			TUNNEL OXIDES
10/042925	January 9,	303.684US4	P-CHANNEL DYNAMIC FLASH
	2002		MEMORY CELLS WITH ULTRATHIN
			TUNNEL OXIDES
10/786726	February 25,	303.680US3	STATIC NVRAM WITH ULTRA THIN
	2004		TUNNEL OXIDES

Respectfully submitted,

LEONARD FORBES ET AL.

By Applicants' Representatives,

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.

P.O. Box 2938

Minneapolis, MN 55402

(612) 373-6944

Date

David C. Peterson

Reg. No. 47,857

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5-18-04

<u>S/N 10/721585</u> <u>PATENT</u>

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Leonard Forbes et al.

Examiner: Unknown

erial No.: 10/721585

Group Art Unit: 2825

Filed: Title: November 25, 2003 Docket: 1303.017US2 TECHNIQUE TO CONTROL TUNNELING CURRENTS IN DRAM

CAPACITORS, CELLS, AND DEVICES

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

In compliance with the duty imposed by 37 C.F.R. § 1.56, and in accordance with 37 C.F.R. §§ 1.97 *et. seq.*, the enclosed materials are brought to the attention of the Examiner for consideration in connection with the above-identified patent application. Applicant respectfully requests that this Supplemental Information Disclosure Statement be entered and the documents listed on the attached Form 1449 be considered by the Examiner and made of record. Pursuant to the provisions of MPEP 609, Applicants request that a copy of the 1449 form, initialed as being considered by the Examiner, be returned to the Applicants with the next official communication.

Pursuant to 37 C.F.R. §1.97(b), it is believed that no fee or statement is required with the Supplemental Information Disclosure Statement. However, if an Office Action on the merits has been mailed, the Commissioner is hereby authorized to charge the required fees to Deposit Account No. 19-0743 in order to have this Supplemental Information Disclosure Statement considered.

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Serial No :10/721585

Filing Date: November 25, 2003

Title: TECHNIQUE TO CONTROL TUNNELING CURRENTS IN DRAM CAPACITORS, CELLS, AND DEVICES

Page 2 Dkt: 1303.017US2

The present application is either a U.S. national patent application filed after June 30, 2003 or

an international application that entered the national stage under 35 U.S.C. § 371 after June 30, 2003.

Thus, Applicant believes that the U.S. Patent & Trademark Office has waived the requirement under

37 C.F.R. 1.98 (a)(2)(i) for submitting a copy of each cited U.S. patent and each U.S. patent

application publication. The waiver is provided in a pre-OG notice from the U.S. Patent &

Trademark Office entitled "Information Disclosure Statements May Be Filed Without Copies of U.S.

Patents and Published Applications in Patent Applications filed after June 30, 2003" and dated July

11, 2003. Applicant acknowledges the requirement to submit copies of foreign patent documents and

non-patent literature in accordance with 37 C.F.R. 1.98(a)(2).

The Examiner is invited to contact the Applicants' Representative at the below-listed

telephone number if there are any questions regarding this communication.

Respectfully submitted,

LEONARD FORBES ET AL.

By their Representatives,

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.

P.O. Box 2938

Minneapolis, MN 55402

(612) 373-6944

Date 5-18-04

 $\mathbf{B}\mathbf{y}$

David C. Peterson

Reg. No. 47,857

CERTIFICATE UNDER 37 CFR 1.8: The undersigned hereby certifies that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail, in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-

1450, on this 19-day of May, 2004.

Nome

Signature

PTO/SB/08A(10-01)

Approved for use through 10/31/2002. OMB 651-0031

US Pate & Trademark Office: U.S. DEPARTMENT OF COMMERCE
collection of information unless it notations a walfs AVID.

Substitute for form 1449A/PTO
INFORMATION DISCLOSURE
STATEMENT BY APPLICANT
(Use as many sheets as necessary)

MAY 2 1 2004

Sheet 1 of TRANSAME.

Complete if Known	
Application Number	10/721585
Filing Date	November 25, 2003
First Named Inventor	Forbes, Leonard
Group Art Unit	2825
Examiner Name	Unknown

Attorney Docket No: 1303.017US2

	US PATENT DOCUMENTS					
Examiner Initial *	USP Document Number	Publication Date	Name of Patentee or Applicant of cited Document	Class	Subclass	Filing Date If Appropriate
	US-2002/0016081A1	02/07/2002	Aloni, E., et al.	438	714	10/15/2001
	US-2003/0001197	01/02/2003	Chang, Y., et al.	257	315	08/30/2002
	US-2003/0201491	10/30/2003	Chung, B.	257	324	05/08/2003
	US-5,408,115	04/18/1995	Chang, K.	257	324	04/04/1994
	US-6,245,613	06/12/2001	Hsu,, et al.			04/24/2000
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	US-6,249,460	06/19/2001	Forbes, Leonard, et al.	365	185.28	02/28/2000
	US-6,265,266	07/24/2001	Dejenfelt, A. T., et al.	438	258	09/27/1996
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	US-6,515,328	02/04/2003	Yang, W., et al.	257	315	02/04/1999
	US-6,583,011	06/24/2003	Xia, L., et al.	438	275	01/11/2000
	US-6,639,835	10/28/2003	Forbes, L.	365	186.14	02/29/2000
	US-6,730,960	05/04/2004	Forbes, L.	257	321	08/30/2001

FOREIGN PATENT DOCUMENTS						
Examiner initials*	Foreign Document No	Publication Date	Name of Patentee or Applicant of cited Document	Class	Subclass	T²

	OTHER DOCUMENTS NON PATENT LITERATURE DOCUMENTS			
Examiner initials*	Cite include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.		T ²	
		TIWARI, SANDIP, "Volatile and Non-Volatile Memories in Silicon with Nano-Crystal Storage", Int'l Electron Devices Meeting: Technical Digest, Washington, DC, (Dec. 1995), 521-524		

EXAMINER

DATE CONSIDERED